

HiPerFRED

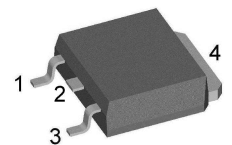
$$\begin{aligned} V_{RRM} &= 600 \text{ V} \\ I_{FAV} &= 6 \text{ A} \\ t_{rr} &= 20 \text{ ns} \end{aligned}$$

High Performance Fast Recovery Diode
 Low Loss and Soft Recovery
 Single Diode

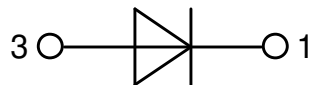
Part number

DSEP6-06AS

Marking on Product: 6P060AS



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-252 (DPak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

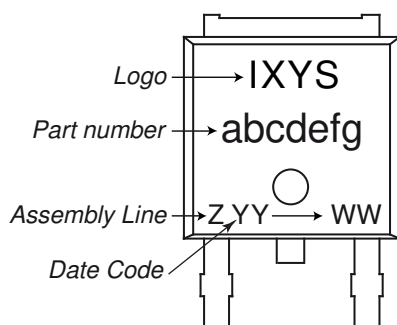
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Fast Diode				Ratings				
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
V _{RSM}	max. non-repetitive reverse blocking voltage	T _{VJ} = 25°C				600	V	
V _{RRM}	max. repetitive reverse blocking voltage	T _{VJ} = 25°C				600	V	
I _R	reverse current, drain current	V _R = 600 V	T _{VJ} = 25°C			50	μA	
		V _R = 600 V	T _{VJ} = 150°C			0.2	mA	
V _F	forward voltage drop	I _F = 6 A	T _{VJ} = 25°C			2.03	V	
		I _F = 12 A				2.22	V	
		I _F = 6 A	T _{VJ} = 150°C			1.34	V	
		I _F = 12 A				1.55	V	
I _{FAV}	average forward current	T _C = 150°C rectangular d = 0.5	T _{VJ} = 175°C			6	A	
V _{F0}	threshold voltage	} for power loss calculation only		T _{VJ} = 175°C		1.00	V	
r _F	slope resistance					34	mΩ	
R _{thJC}	thermal resistance junction to case					2.8	K/W	
R _{thCH}	thermal resistance case to heatsink				0.50		K/W	
P _{tot}	total power dissipation	T _C = 25°C				55	W	
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine; V _R = 0 V		T _{VJ} = 45°C		40	A	
C _J	junction capacitance	V _R = 400 V f = 1 MHz		T _{VJ} = 25°C	5		pF	
I _{RM}	max. reverse recovery current	} I _F = 6 A; V _R = 300 V -di _F /dt = 200 A/μs		T _{VJ} = 25 °C	3		A	
				T _{VJ} = 100 °C	5		A	
t _{rr}	reverse recovery time			T _{VJ} = 25 °C	20		ns	
				T _{VJ} = 100 °C	80		ns	

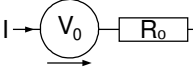
Package TO-252 (DPak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			20	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				0.3		g
F_c	mounting force with clip		20		60	N

Product Marking



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEP6-06AS-TRL	6P060AS	Tape & Reel	2500	509806
Alternative	DSEP6-06AS-TUB	6P060AS	Tube	70	524993

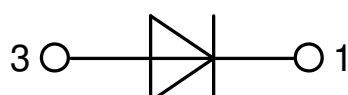
Similar Part	Package	Voltage class
DSEP6-06BS	TO-252AA (DPak)	600

Equivalent Circuits for Simulation		* on die level	$T_{VJ} = 175^{\circ}\text{C}$
	Fast Diode		
	$V_{0\text{ max}}$	threshold voltage	1 V
	$R_{0\text{ max}}$	slope resistance *	30 mΩ

Outlines TO-252 (DPak)


Dim	Millimeters		Inches	
	min	max	min	max
A	2.20	2.40	0.087	0.094
A1	2.10	2.50	0.083	0.098
b	0.66	0.86	0.026	0.034
b2	-	0.96	-	0.038
b3	5.04	5.64	0.198	0.222
b4	4.34 BSC		0.171 BSC	
b5	0.50 BSC		0.020 BSC	
c	0.40	0.86	0.016	0.034
D	5.90	6.30	0.232	0.248
E	6.40	6.80	0.252	0.268
e	2.10	2.50	0.083	0.098
H	9.20	10.10	0.362	0.398
L	0.55	1.28	0.022	0.050
L1	2.50	2.90	0.098	0.114
L2	0.40	0.60	0.016	0.024
L3	0.50	0.90	0.020	0.035
L4	0.60	1.00	0.024	0.039
L5	0.82	1.22	0.032	0.048
L6	0.79	0.99	0.031	0.039
L7	0.81	1.01	0.032	0.040
L8	0.40	0.80	0.016	0.031
L9	1.50 BSC		0.059 BSC	
Ø P	1.00 BSC		0.039 BSC	

Recommended
min. foot print



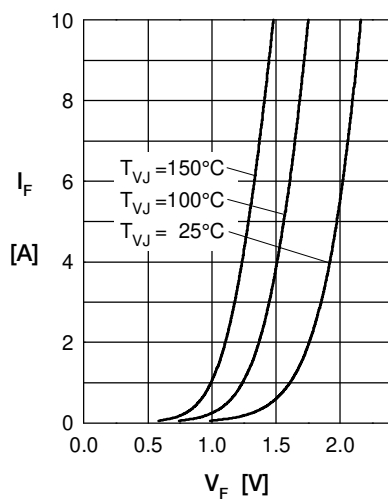
Fast Diode


Fig. 1 Forward current
 I_F versus V_F

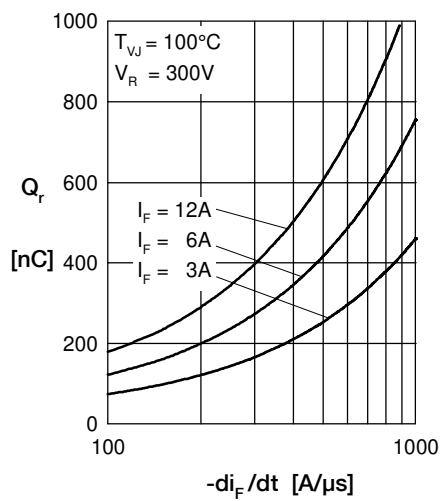


Fig. 2 Typ. reverse recov. charge
 Q_r versus $-di_F/dt$

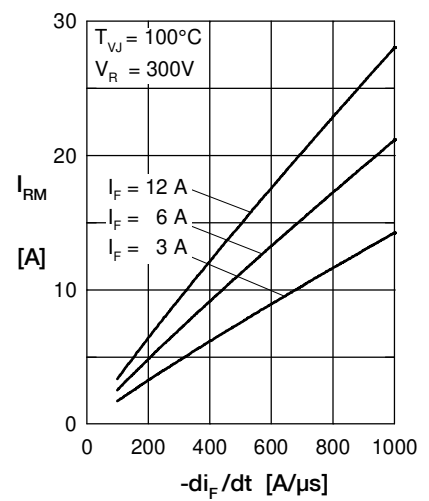


Fig. 3 Typ. peak reverse current
 I_{RM} versus $-di_F/dt$

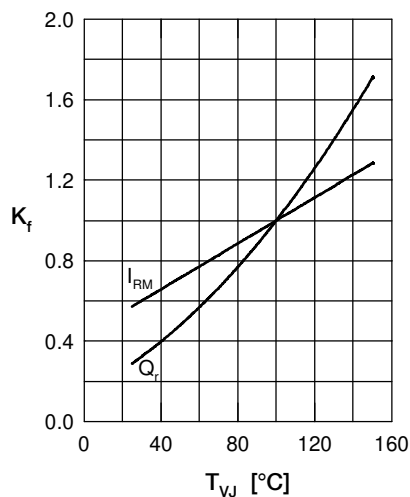


Fig. 4 Typ. dynamic parameters
 Q_r , I_{RM} versus T_{VJ}

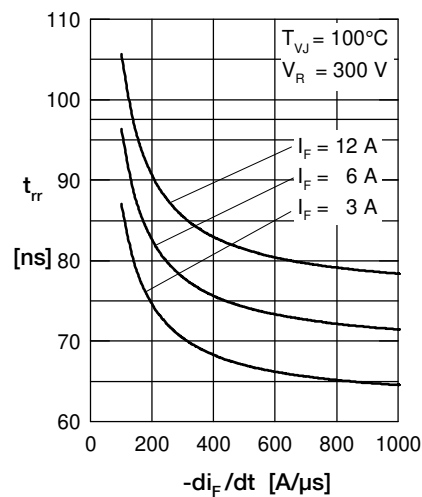


Fig. 5 Recovery time
 t_{rr} versus $-di_F/dt$

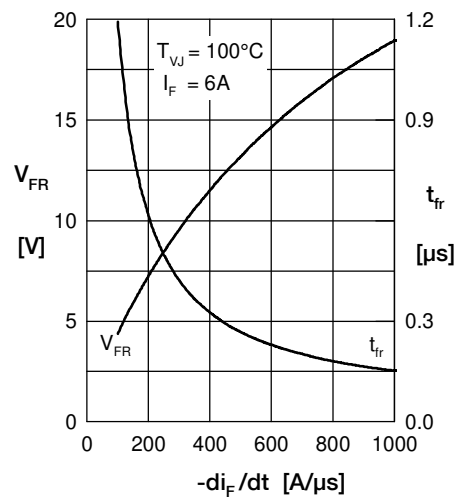


Fig. 6 Typ. peak forward voltage
 V_{FR} and t_{fr} versus di_F/dt

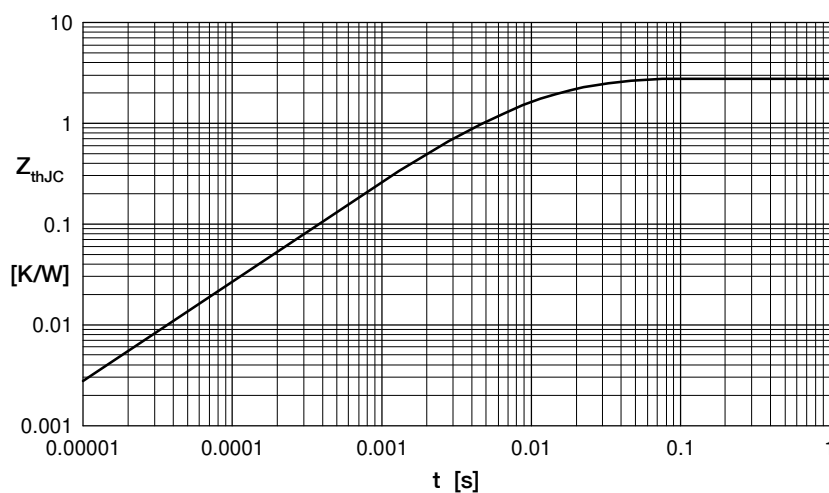


Fig. 7 Transient thermal resistance junction to case